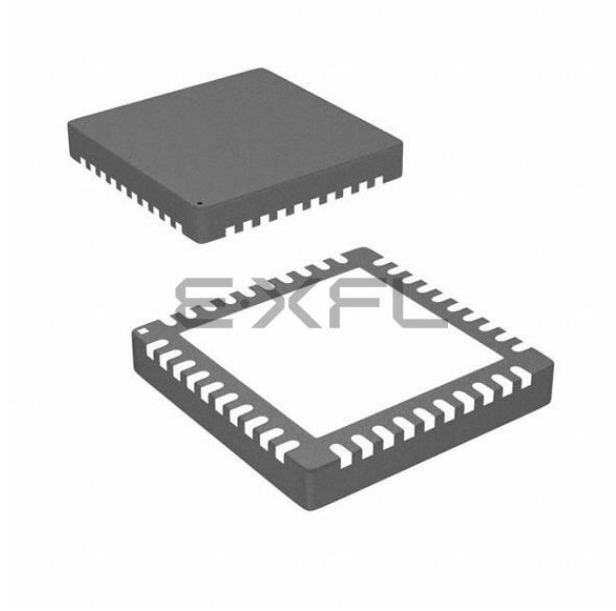

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Details	
Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	50MHz
Connectivity	I²C, LINbus, SCI, SPI
Peripherals	LVD, PWM, WDT
Number of I/O	26
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 10x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-VFQFN Exposed Pad
Supplier Device Package	32-QFN-EP (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08qe32cfm

Table of Contents

Revision History

To provide the most up-to-date information, the revision of our documents on the World Wide Web will be the most current. Your printed copy may be an earlier revision. To verify you have the latest information available, refer to:

http://freescale.com/

The following revision history table summarizes changes contained in this document.

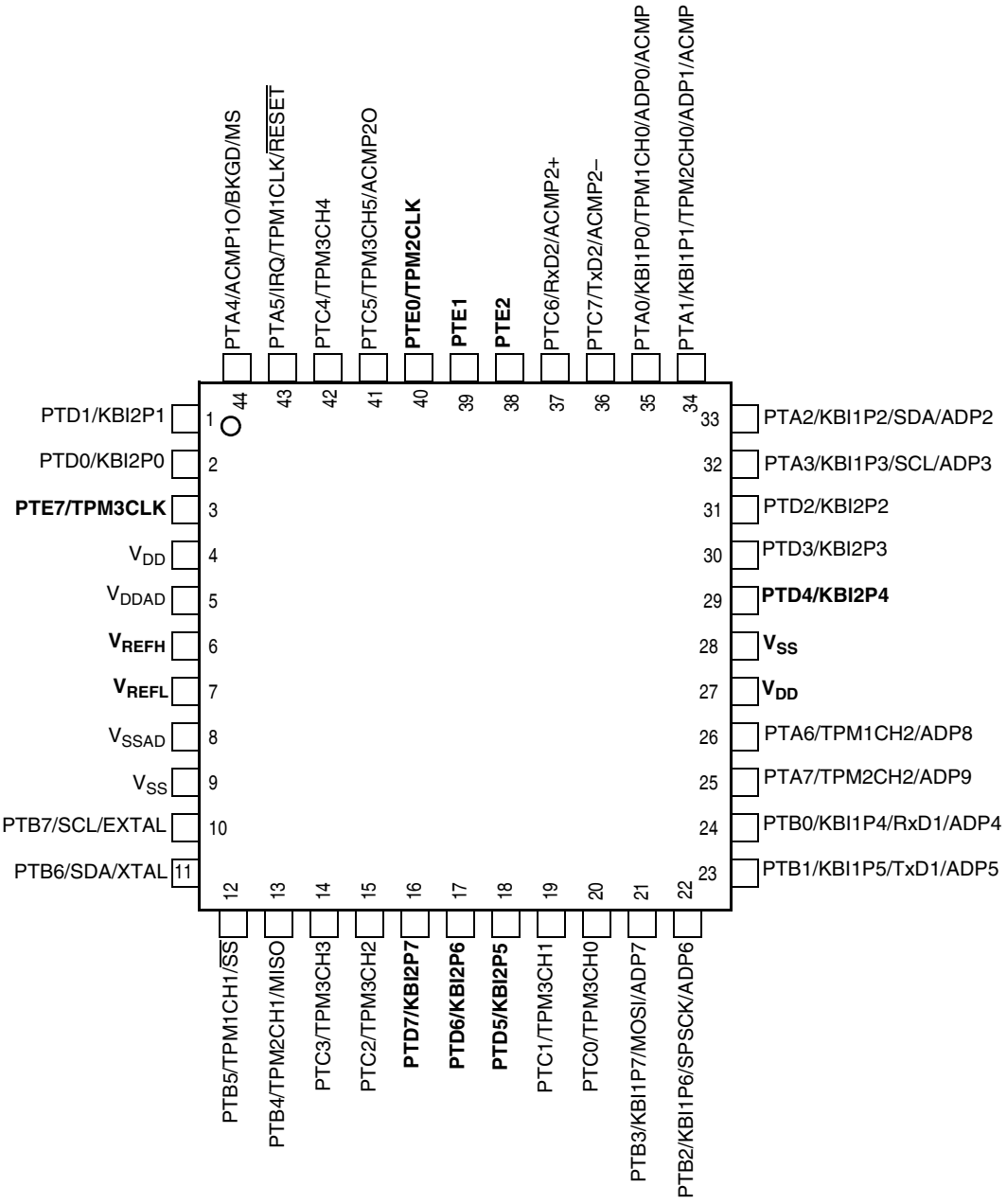
Revision	Date	Description of Changes
1	7/2/2008	Initial public released.
2	10/7/2008	Updated the Stop2 and Stop3 mode supply current, and RI_{DD} in FEI mode with all modules on at 25.165 MHz in the Table 8 Supply Current Characteristics. Replaced the stop mode adders section from Table 8 with an individual Table 9 Stop Mode Adders with new specifications.
3	11/4/2008	Updated operating voltage in Table 7.
4	5/4/2009	Added 10×10 mm information to 44 LQFP in the front page. In Table 7, added $\|I_{OZTOT}\|$. In Table 11, updated typicals and Max. for $t_{IRST.}$ In Table 16, removed the Rev. Voltage High item. Updated Table 17.
5	8/27/2009	Updated f_{int_t} and f_{int_ut} in the Table 11.
6	10/13/2009	Corrected the package size descriptions on the cover
7	9/16/2011	Added new package of 32-pin QFN.

Related Documentation

Find the most current versions of all documents at: http://www.freescale.com

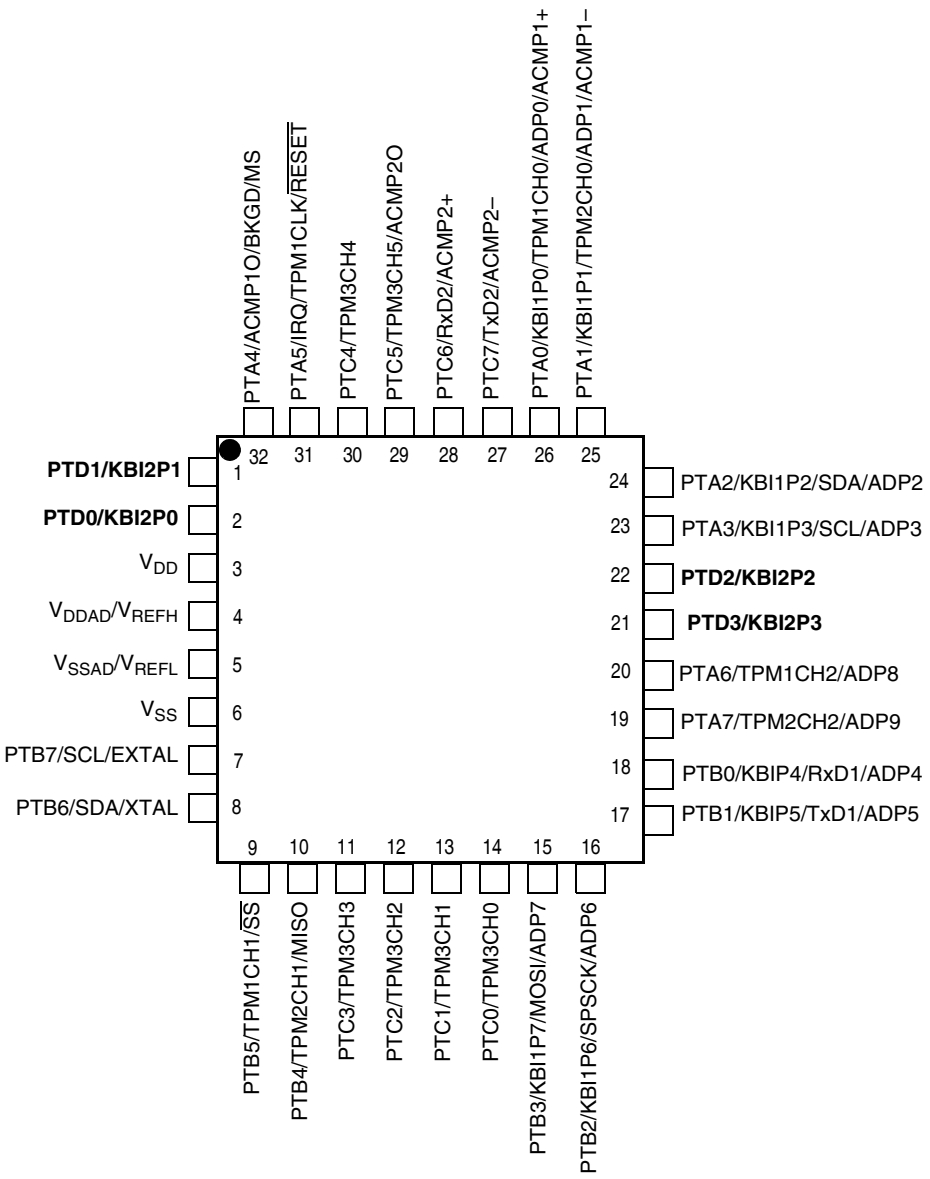
Reference Manual (MC9S08QE32RM)

Contains extensive product information including modes of operation, memory, resets and interrupts, register definition, port pins, CPU, and all module information.



Pins in **bold** are lost in the next lower pin count package.

Figure 3. 44-Pin LQFP



Pins in **bold** are lost in the next lower pin count package.

Figure 4. 32-Pin LQFP/QFN

Table 1. MC9S08QE32 Series Pin Assignment by Package and Pin Sharing Priority (continued)

Pin Number				<-- Lowest **Priority** --> Highest				
48	**44**	**32**	**28**	**Port Pin**	**Alt 1**	**Alt 2**	**Alt 3**	**Alt 4**
19	17	—	—	PTD6	KBI2P6			
20	18	—	—	PTD5	KBI2P5			
21	19	13	15	PTC1	TPM3CH1			
22	20	14	16	PTC0	TPM3CH0			
23	21	15	17	PTB3	KBI1P7	MOSI[2]		ADP7
24	22	16	18	PTB2	KBI1P6	SPSCK[2]		ADP6
25	23	17	19	PTB1	KBI1P5	TxD1		ADP5
26	24	18	20	PTB0	KBI1P4	RxD1		ADP4
27	25	19	21	PTA7	TPM2CH2			ADP9
28	26	20	22	PTA6	TPM1CH2			ADP8
29	—	—	—	PTE4				
30	27	—	—					V_{DD}
31	28	—	—					V_{SS}
32	29	—	—	PTD4	KBI2P4			
33	30	21	—	PTD3	KBI2P3			
34	31	22	—	PTD2	KBI2P2			
35	32	23	23	PTA3	KBI1P3	SCL[1]		ADP3
36	33	24	24	PTA2	KBI1P2	SDA[1]		ADP2
37	34	25	25	PTA1	KBI1P1	TPM2CH0	ADP1[3]	ACMP1–[3]
38	35	26	26	PTA0	KBI1P0	TPM1CH0	ADP0[3]	ACMP1+[3]
39	36	27	27	PTC7	TxD2			ACMP2–
40	37	28	28	PTC6	RxD2			ACMP2+
41	—	—	—	PTE3	$\overline{SS}$[2]			
42	38	—	—	PTE2	MISO[2]			
43	39	—	—	PTE1	MOSI[2]			
44	40	—	—	PTE0	TPM2CLK	SPSCK[2]		
45	41	29	1	PTC5	TPM3CH5			ACMP2O
46	42	30	2	PTC4	TPM3CH4			
47	43	31	3	PTA5	IRQ	TPM1CLK	$\overline{RESET}$	
48	44	32	4	PTA4	ACMP1O	BKGD	MS	

1 IIC pins, SCL and SDA can be repositioned using IICPS in SOPT2; default reset locations are PTA3 and PTA2.

2 SPI pins ($\overline{SS}$, MISO, MOSI, and SPSCK) can be repositioned using SPIPS in SOPT2. Default locations are PTB5, PTB4, PTB3, and PTB2.

3 If ADC and ACMP1 are enabled, both modules will have access to the pin.

Table 3. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	–0.3 to +3.8	V
Maximum current into V_{DD}	I_{DD}	120	mA
Digital input voltage	V_{In}	–0.3 to V_{DD} + 0.3	V
Instantaneous maximum current Single pin limit (applies to all port pins)[1, 2, 3]	I_D	±25	mA
Storage temperature range	T_{stg}	–55 to 150	°C

1 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.

2 All functional non-supply pins, except for PTA5 are internally clamped to V_{SS} and V_{DD}.

3 Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low (which would reduce overall power consumption).

3.4 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 7. DC Characteristics

Num	C	Characteristic	Symbol	Condition	Min	Typical[1]	Max	Unit
1		Operating Voltage V_{DD} rising V_{DD} falling			 2.0 1.8	—	3.6	V
2	C	Output high voltage[2] — All I/O pins, low-drive strength	V_{OH}	1.8 V, I_{Load} = –2 mA	V_{DD} – 0.5	—	—	V
	P	All I/O pins, high-drive strength		2.7 V, I_{Load} = –10 mA	V_{DD} – 0.5	—	—	
	T			2.3 V, I_{Load} = –6 mA	V_{DD} – 0.5	—	—	
	C			1.8V, I_{Load} = –3 mA	V_{DD} – 0.5	—	—	
3	D	Output high current — Max total I_{OH} for all ports	I_{OHT}		—	—	100	mA
4	C	Output low voltage — All I/O pins, low-drive strength	V_{OL}	1.8 V, I_{Load} = 2 mA	—	—	0.5	V
	P	All I/O pins, high-drive strength		2.7 V, I_{Load} = 10 mA	—	—	0.5	
	T			2.3 V, I_{Load} = 6 mA	—	—	0.5	
	C			1.8 V, I_{Load} = 3 mA	—	—	0.5	
5	D	Output low current — Max total I_{OL} for all ports	I_{OLT}		—	—	100	mA
6	P	Input high voltage — all digital inputs	V_{IH}	V_{DD} > 2.3 V	0.70 x V_{DD}	—	—	V
	C			V_{DD} ≤ 1.8 V	0.85 x V_{DD}	—	—	
7	P	Input low voltage — all digital inputs	V_{IL}	V_{DD} > 2.7 V	—	—	0.35 x V_{DD}	
	C			V_{DD} ≤ 1.8 V	—	—	0.30 x V_{DD}	
8	C	Input hysteresis — all digital inputs	V_{hys}		0.06 x V_{DD}	—	—	mV
9	P	Input leakage current — all input only pins (Per pin)	$\lvert I_{In} \rvert$	V_{In} = V_{DD} or V_{SS}	—	—	1	μA
10	P	Hi-Z (off-state) leakage current — all input/output (per pin)	$\lvert I_{OZ} \rvert$	V_{In} = V_{DD} or V_{SS}	—	—	1	μA
11	C	Total leakage combined for all inputs and Hi-Z pins — All input only and I/O	$\lvert I_{OZTOT} \rvert$	V_{In} = V_{DD} or V_{SS}	—	—	2	μA
11	P	Pullup, Pulldown resistors — all digital inputs, when enabled	R_{PU}, R_{PD}		17.5	—	52.5	kΩ
12	D	DC injection current [3, 4, 5] — Single pin limit	I_{IC}	V_{IN} < V_{SS}, V_{IN} > V_{DD}	–0.2	—	0.2	mA
		Total MCU limit, includes sum of all stressed pins			–5	—	5	mA
13	C	Input Capacitance, all pins	C_{In}		—	—	8	pF
14	C	RAM retention voltage	V_{RAM}		—	0.6	1.0	V
15	C	POR re-arm voltage[6]	V_{POR}		0.9	1.4	2.0	V

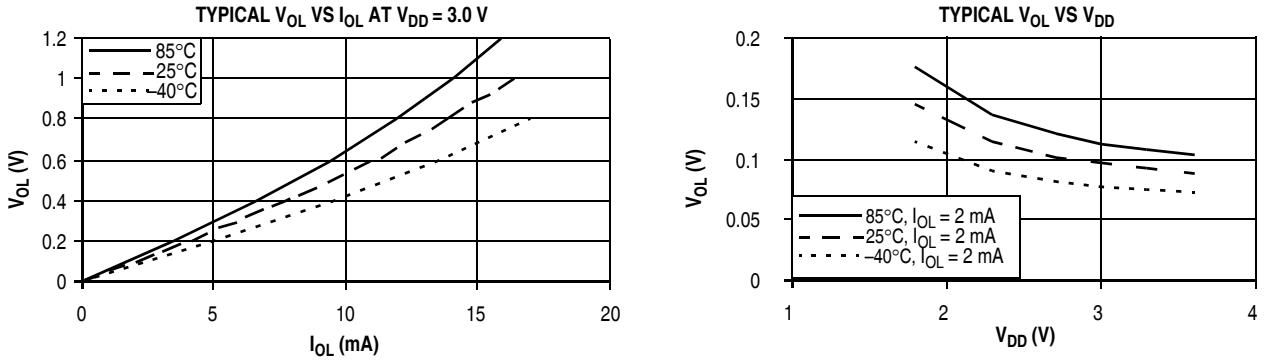


Figure 7. Typical Low-Side Driver (Sink) Characteristics — Low Drive (PTxDSn = 0)

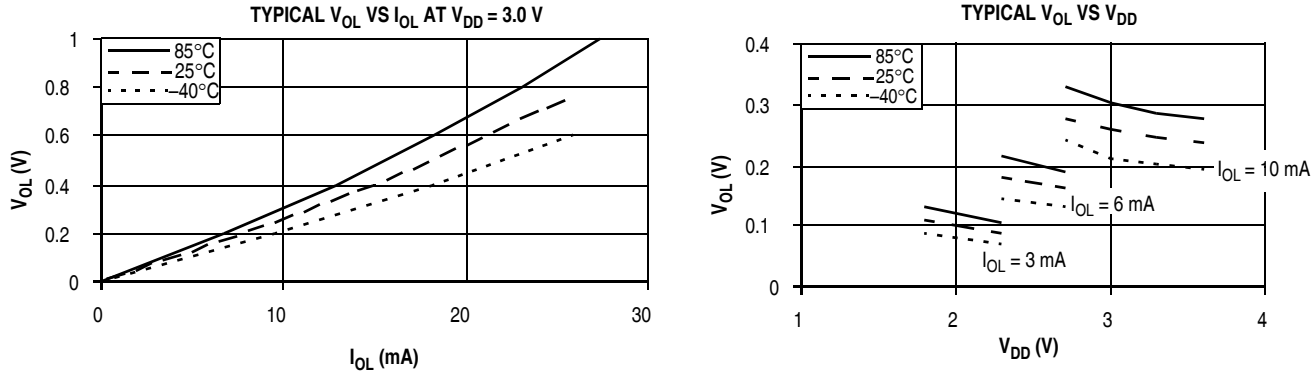


Figure 8. Typical Low-Side Driver (Sink) Characteristics — High Drive (PTxDSn = 1)

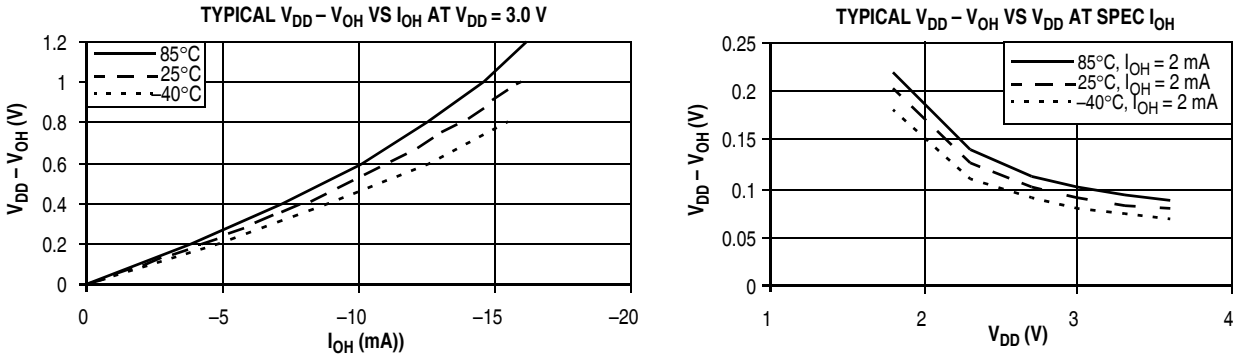


Figure 9. Typical High-Side (Source) Characteristics — Low Drive (PTxDSn = 0)

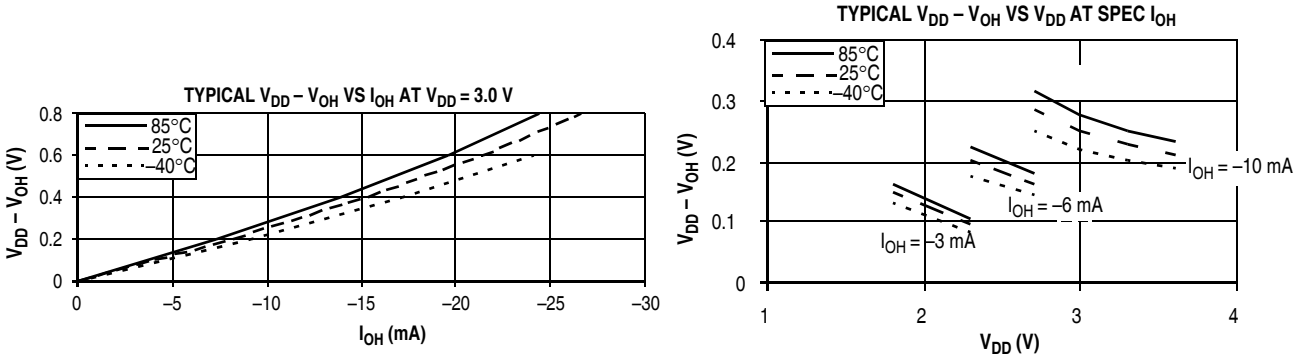


Figure 10. Typical High-Side (Source) Characteristics — High Drive (PTxDSn = 1)

3.7 Supply Current Characteristics

This section includes information about power supply current in various operating modes.

Table 8. Supply Current Characteristics

Num	C	Parameter	Symbol	Bus Freq	V_{DD} (V)	Typical[1]	Max	Unit	Temp (°C)
1	P	Run supply current FEI mode, all modules on	RI_{DD}	25.165 MHz	3	13	14	mA	–40 to 25
	P					14	15		85
	T			20 MHz		13.75	—		–40 to 85
	T			8 MHz		5.59	—		
	T			1 MHz		1.03	—		
2	C	Run supply current FEI mode, all modules off	RI_{DD}	25.165 MHz	3	11.5	12.3	mA	–40 to 85
	T			20 MHz		9.5	—		
	T			8 MHz		4.6	—		
	T			1 MHz		1.0	—		
3	T	Run supply current LPRS = 0, all modules off	RI_{DD}	16 kHz FBILP	3	152	—	μA	–40 to 85
	T			16 kHz FBELP		115	—		
4	T	Run supply current LPRS = 1, all modules off, running from Flash	RI_{DD}	16 kHz FBELP	3	21.9	—	μA	–40 to 85
	T	Run supply current LPRS = 1, all modules off, running from RAM				7.3	—		
5	C	Wait mode supply current FEI mode, all modules off	WI_{DD}	25.165 MHz	3	5.74	6.00	mA	–-40 to 85
	T			20 MHz		4.57	—		
	T			8 MHz		2	—		
	T			1 MHz		0.73	—		

Table 8. Supply Current Characteristics (continued)

Num	C	Parameter		Symbol	Bus Freq	V_{DD} (V)	Typical[1]	Max	Unit	Temp (°C)
6	P	Stop2 mode supply current		$S2I_{DD}$	—	3	0.35	0.65	μA	–40 to 25C
	C				—		0.8	1.0		70
	P				—		2.0	4.5		85
	C				—	2	0.25	0.50		–40 to 25
	C				—		0.65	0.85		70
	C				—		1.5	3.5		85
7	P	Stop3 mode supply current no clocks active		$S3I_{DD}$	—	3	0.45	1.00	μA	–40 to 25
	C				—		1.5	2.3		70
	P				—		4	8		85
	C				—	2	0.35	0.70		–40 to 25
	C				—		1	2		70
	C				—		3.5	6.0		85
8	T	Low power mode adders:	EREFSTEN=1		32 kHz	3	500	—	nA	–40 to 85
9	T		IREFSTEN=1		32 kHz		70	—	μA	
10	T		TPM PWM		100 Hz		12	—	μA	
11	T		SCI, SPI, or IIC		300 bps		15	—	μA	
12	T		RTC using LPO		1 kHz		200	—	nA	
13	T		RTC using ICSERCLK		32 kHz		1	—	μA	
14	T		LVD		n/a		100	—	μA	
15	T		ACMP		n/a		20	—	μA	

[1] Data in Typical column was characterized at 3.0 V, 25 °C or is typical recommended value.

Table 9. Stop Mode Adders

Num	C	Parameter	Condition	Temperature				Units
				–40°C	**25**°C	**70**°C	**85**°C	
1	T	LPO	—	50	75	100	150	nA
2	T	ERREFSTEN	RANGE = HGO = 0	1000	1000	1100	1500	nA
3	T	IREFSTEN[1]	—	63	70	77	81	μA
4	T	RTC	Does not include clock source current	50	75	100	150	nA
5	T	LVD[1]	LVDSE = 1	90	100	110	115	μA
6	T	ACMP[1]	Not using the bandgap (BGBE = 0)	18	20	22	23	μA
7	T	ADC[1]	ADLPC = ADLSMP = 1 Not using the bandgap (BGBE = 0)	95	106	114	120	μA

[1] Not available in stop2 mode.

3.8 External Oscillator (XOSCVLP) Characteristics

Reference Figure 11 and Figure 12 for crystal or resonator circuits.

Table 10. XOSC and ICS Specifications (Temperature Range = –40 to 85°C Ambient)

Num	C	Characteristic	Symbol	Min	Typical[1]	Max	Unit
1	C	Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) Low range (RANGE = 0) High range (RANGE = 1), high gain (HGO = 1) High range (RANGE = 1), low power (HGO = 0)	 f_{lo} f_{hi} f_{hi}	 32 1 1	 — — —	 38.4 16 8	 kHz MHz MHz
2	D	Load capacitors Low range (RANGE=0), low power (HGO=0) Other oscillator settings	 C_1 C_2	 See Note [2] See Note [3]			
3	D	Feedback resistor Low range, low power (RANGE=0, HGO=0)[2] Low range, High Gain (RANGE=0, HGO=1) High range (RANGE=1, HGO=X)	R_F	 — — —	 — 10 1	 — — —	MΩ
4	D	Series resistor — Low range, low power (RANGE = 0, HGO = 0)[2] Low range, high gain (RANGE = 0, HGO = 1) High range, low power (RANGE = 1, HGO = 0) High range, high gain (RANGE = 1, HGO = 1) ≥ 8 MHz 4 MHz 1 MHz	R_S	 — — — — — —	 — 100 0 0 0 0	 — — — 0 10 20	kΩ
5	C	Crystal start-up time [4] Low range, low power Low range, high power High range, low power High range, high power	 t_{CSTL} t_{CSTH} 	 — — — —	 200 400 5 15	 — — — —	 ms
6	D	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) FEE mode FBE or FBELP mode	f_{extal}	0.03125 0	— —	40 40	MHz MHz

[1] Data in Typical column is characterized at 3.0 V, 25 °C or is typical recommended value.

[2] Load capacitors (C_1,C_2), feedback resistor (R_F) and series resistor (R_S) are incorporated internally when RANGE=HGO=0.

[3] See crystal or resonator manufacturer's recommendation.

[4] Proper PC board layout procedures must be followed to achieve specifications.

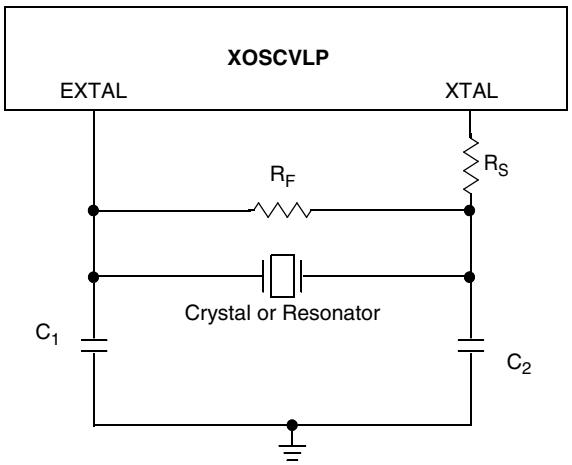


Figure 11. Typical Crystal or Resonator Circuit: High Range and Low Range/High Gain

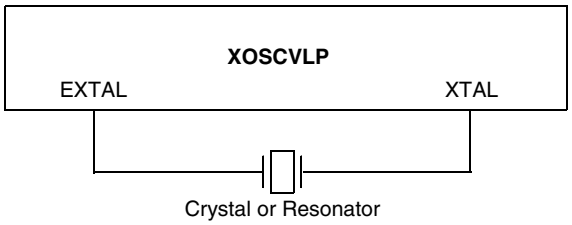


Figure 12. Typical Crystal or Resonator Circuit: Low Range/Low Power

3.9 Internal Clock Source (ICS) Characteristics

Table 11. ICS Frequency Specifications (Temperature Range = –40 to 85°C Ambient)

Num	C	Characteristic		Symbol	Min	Typical[1]	Max	Unit
1	P	Average internal reference frequency — factory trimmed		f_{int_t}	—	32.768	—	kHz
2	C	Average internal reference frequency — untrimmed		f_{int_ut}	31.25	—	39.06	kHz
3	T	Internal reference start-up time		t_{IRST}	—	5	10	µs
4	P	DCO output frequency trimmed[2]	Low range (DFR = 00)	f_{dco_u}	16	—	20	MHz
	P		Mid range (DFR = 01)		32	—	40	
	P		High range (DFR = 10)		48	—	60	
5	P	DCO output frequency[2] reference = 32768 Hz and DMX32 = 1	Low range (DFR = 00)	f_{dco_DMX32}	—	19.92	—	MHz
	P		Mid range (DFR = 01)		—	39.85	—	
	P		High range (DFR = 10)		—	59.77	—	
6	C	Resolution of trimmed DCO output frequency at fixed voltage and temperature (using FTRIM)		$\Delta f_{dco\_res\_t}$	—	±0.1	±0.2	$\%f_{dco}$
7	C	Resolution of trimmed DCO output frequency at fixed voltage and temperature (not using FTRIM)		$\Delta f_{dco\_res\_t}$	—	±0.2	±0.4	$\%f_{dco}$

Table 11. ICS Frequency Specifications (Temperature Range = –40 to 85°C Ambient) (continued)

Num	C	Characteristic	Symbol	Min	Typical[1]	Max	Unit
8	C	Total deviation of trimmed DCO output frequency over voltage and temperature	Δf_{dco_t}	—	0.5 –1.0	±2	$\%f_{dco}$
9	C	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0 °C to 70 °C	Δf_{dco_t}	—	±0.5	±1	$\%f_{dco}$
10	C	FLL acquisition time[3]	$t_{Acquire}$	—	—	1	ms
11	C	Long term jitter of DCO output clock (averaged over 2-ms interval)[4]	C_{Jitter}	—	0.02	0.2	$\%f_{dco}$

1 Data in Typical column is characterized at 3.0 V, 25 °C or is typical recommended value.

2 The resulting bus clock frequency must not exceed the maximum specified bus clock frequency of the device.

3 This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

4 Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{Bus}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V_{DD} and V_{SS} and variation in crystal oscillator frequency increase the C_{Jitter} percentage for a given interval.

3.10 AC Characteristics

This section describes timing characteristics for each peripheral system.

3.10.1 Control Timing

Table 12. Control Timing

Num	C	Rating	Symbol	Min	Typical[1]	Max	Unit
1	D	Bus frequency ($t_{cyc} = 1/f_{Bus}$) $V_{DD} \le 2.1V$ $2.1<V_{DD} \le 2.4V$ $V_{DD} > 2.4Vs$	f_{Bus}	DC	—	10 20 25.165	MHz
2	D	Internal low power oscillator period	t_{LPO}	700	—	1300	µs
3	D	External reset pulse width[2]	t_{extrst}	100	—	—	ns
4	D	Reset low drive	t_{rstdrv}	$34 \times t_{cyc}$	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes	t_{MSSU}	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes [3]	t_{MSH}	100	—	—	µs
7	D	IRQ pulse width Asynchronous path[2] Synchronous path[4]	t_{ILIH}, t_{IHIL}	100 $1.5 \times t_{cyc}$	— —	— —	ns

Table 12. Control Timing (continued)

Num	C	Rating	Symbol	Min	Typical[1]	Max	Unit
8	D	Keyboard interrupt pulse width Asynchronous path[2] Synchronous path[5]	t_{ILIH}, t_{IHIL}	 100 1.5 × t_{cyc}	 — —	 — —	ns
9	C	Port rise and fall time — Low output drive (PTxDS = 0) (load = 50 pF)[5] Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t_{Rise}, t_{Fall}	 — —	 8 31	 — —	ns
		Port rise and fall time — High output drive (PTxDS = 1) (load = 50 pF) Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t_{Rise}, t_{Fall}	 — —	 7 24	 — —	ns
10	C	Voltage regulator recovery time	t_{VRR}	—	4	—	µs

1 Typical values are based on characterization data at V_{DD} = 3.0 V, 25 °C unless otherwise stated.

2 This is the shortest pulse that is guaranteed to be recognized as a reset pin request. Shorter pulses are not guaranteed to override reset requests from internal sources.

3 To enter BDM mode following a POR, BKGD/MS must be held low during the power-up and for a hold time of t_{MSH} after V_{DD} rises above V_{LVD}.

4 This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

5 Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range –40 °C to 85 °C.

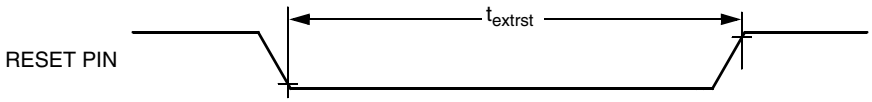


Figure 13. Reset Timing

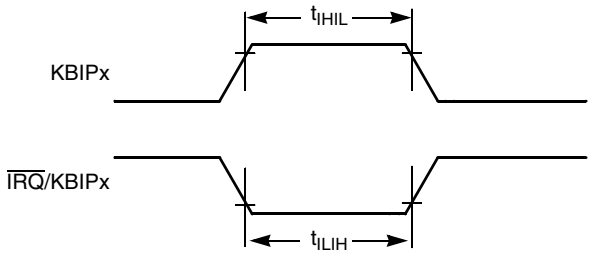


Figure 14. IRQ/KBIPx Timing

3.10.2 TPM Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 13. TPM Input Timing

No.	C	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	f_{TCLK}	0	$f_{Bus}/4$	Hz
2	D	External clock period	t_{TCLK}	4	—	t_{cyc}
3	D	External clock high time	t_{clkh}	1.5	—	t_{cyc}
4	D	External clock low time	t_{clkl}	1.5	—	t_{cyc}
5	D	Input capture pulse width	t_{ICPW}	1.5	—	t_{cyc}

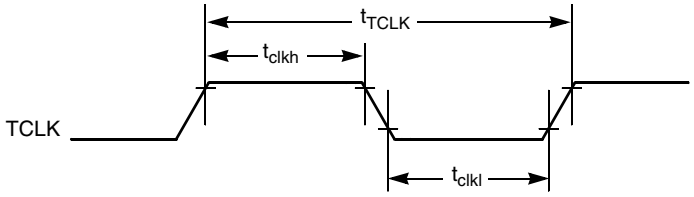


Figure 15. Timer External Clock

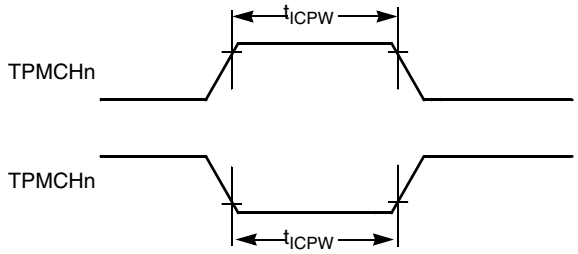


Figure 16. Timer Input Capture Pulse

3.10.3 SPI Timing

Table 14 and Figure 17 through Figure 20 describe the timing requirements for the SPI system.

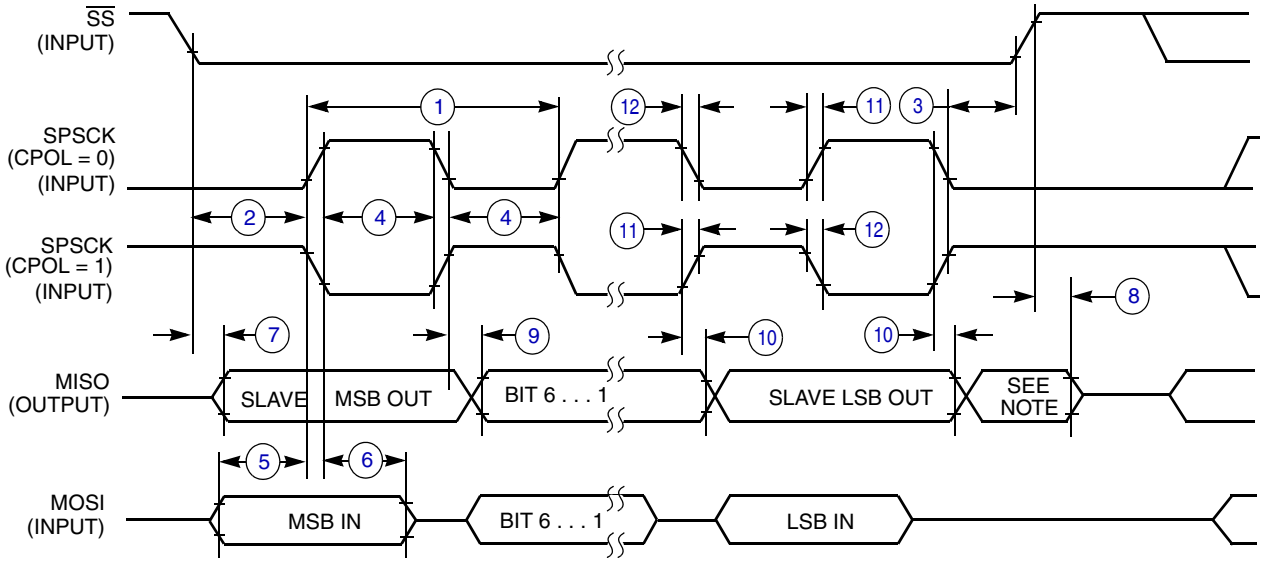
Table 14. SPI Timing

No.	C	Function	Symbol	Min	Max	Unit
—	D	Operating frequency Master Slave	f_{op}	$f_{Bus}/2048$ 0	$f_{Bus}/2^1$ $f_{Bus}/4$	Hz
1	D	SPSCK period Master Slave	t_{SPSCK}	2 4	2048 —	t_{cyc} t_{cyc}
2	D	Enable lead time Master Slave	t_{Lead}	1/2 1	— —	t_{SPSCK} t_{cyc}
3	D	Enable lag time Master Slave	t_{Lag}	1/2 1	— —	t_{SPSCK} t_{cyc}

Table 14. SPI Timing (continued)

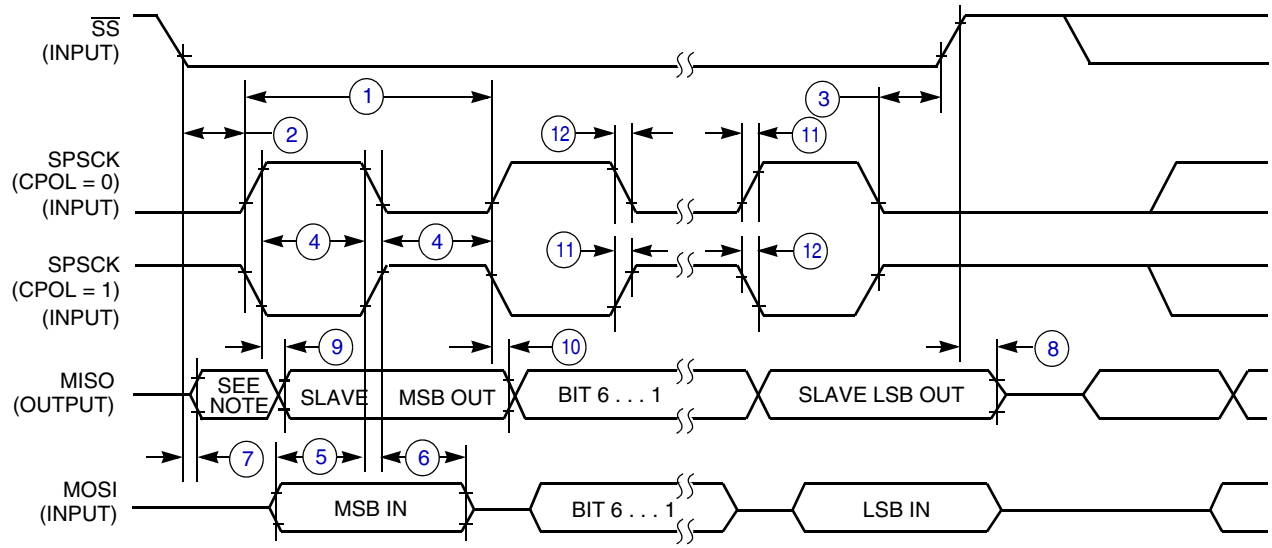
No.	C	Function	Symbol	Min	Max	Unit
4	D	Clock (SPSCK) high or low time Master Slave	t_{WSPSCK}	 $t_{cyc} - 30$ $t_{cyc} - 30$	 1024 t_{cyc} —	 ns ns
5	D	Data setup time (inputs) Master Slave	t_{SU}	 15 15	 — —	 ns ns
6	D	Data hold time (inputs) Master Slave	t_{HI}	 0 25	 — —	 ns ns
7	D	Slave access time	t_a	—	1	t_{cyc}
8	D	Slave MISO disable time	t_{dis}	—	1	t_{cyc}
9	D	Data valid (after SPSCK edge) Master Slave	t_v	 — —	 25 25	 ns ns
10	D	Data hold time (outputs) Master Slave	t_{HO}	 0 0	 — —	 ns ns
11	D	Rise time Input Output	 t_{RI} t_{RO}	 — —	 $t_{cyc} - 25$ 25	 ns ns
12	D	Fall time Input Output	 t_{FI} t_{FO}	 — —	 $t_{cyc} - 25$ 25	 ns ns

1 Max operating frequency limited to 8 MHz when input filter disabled and high output drive strength enabled. Max operating frequency limited to 5 MHz when input filter enabled and high output drive strength disabled.



NOTE:
1. Not defined but normally MSB of character just received

Figure 19. SPI Slave Timing (CPHA = 0)



NOTE:
1. Not defined but normally LSB of character just received

Figure 20. SPI Slave Timing (CPHA = 1)

3.11 Analog Comparator (ACMP) Electricals

Table 15. Analog Comparator Electrical Specifications

C	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage	V_{DD}	1.8	—	3.6	V
P	Supply current (active)	I_{DDAC}	—	20	35	μA
D	Analog input voltage	V_{AIN}	V_{SS} – 0.3	—	V_{DD}	V
P	Analog input offset voltage	V_{AIO}	—	20	40	mV
C	Analog comparator hysteresis	V_H	3.0	9.0	15.0	mV
P	Analog input leakage current	I_{ALKG}	—	—	1.0	μA
C	Analog comparator initialization delay	t_{AINIT}	—	—	1.0	μs

3.12 ADC Characteristics

Table 16. 12-Bit ADC Operating Conditions

C	Characteristic	Conditions	Symb	Min	Typical[1]	Max	Unit	Comment
D	Supply voltage	Absolute	V_{DDAD}	1.8	—	3.6	V	—
		Delta to V_{DD} (V_{DD} – V_{DDAD})[2]	ΔV_{DDAD}	–100	0	100	mV	—
D	Ground voltage	Delta to V_{SS} (V_{SS} – V_{SSAD})[2]	ΔV_{SSAD}	–100	0	100	mV	—
D	Input voltage	—	V_{ADIN}	V_{REFL}	—	V_{REFH}	V	—
C	Input capacitance	—	C_{ADIN}	—	4.5	5.5	pF	—
C	Input resistance	—	R_{ADIN}	—	5	7	kΩ	—
C	Analog source resistance	12-bit mode f_{ADCK} > 4 MHz f_{ADCK} < 4 MHz	R_{AS}	 — —	 — —	 2 5	kΩ	External to MCU
		10-bit mode f_{ADCK} > 4 MHz f_{ADCK} < 4 MHz		 — —	 — —	 5 10		
		8-bit mode (all valid f_{ADCK})		—	—	10		
D	ADC conversion clock freq.	High speed (ADLPC = 0)	f_{ADCK}	0.4	—	8.0	MHz	—
		Low power (ADLPC = 1)		0.4	—	4.0		

1 Typical values assume V_{DDAD} = 3.0 V, Temp = 25 °C, f_{ADCK}=1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

2 DC potential difference.

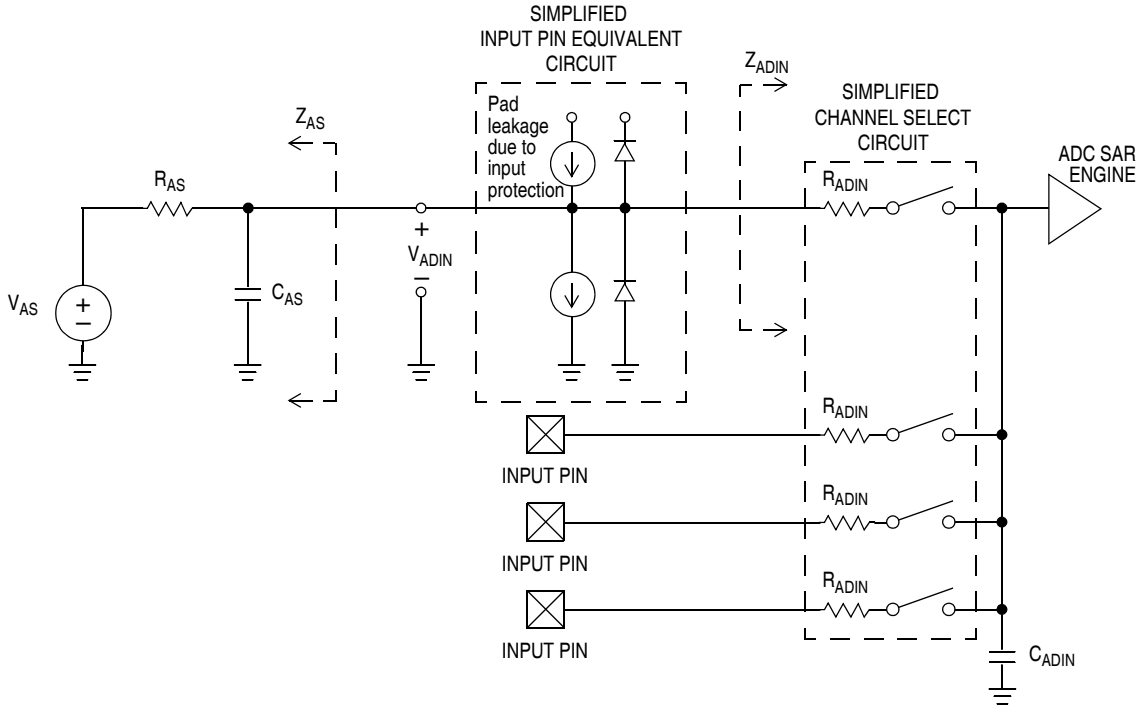


Figure 21. ADC Input Impedance Equivalency Diagram

Table 17. ADC Characteristics (V_{REFH} = V_{DDAD}, V_{REFL} = V_{SSAD})

C	Characteristic	Conditions	Symbol	Min	Typ[1]	Max	Unit	Comment
T	Supply current ADLPC = 1 ADLSMP = 1 ADCO = 1		I_{DDAD}	—	120	—	μA	
T	Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		I_{DDAD}	—	202	—	μA	
T	Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		I_{DDAD}	—	288	—	μA	
P	Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		I_{DDAD}	—	0.532	1	mA	
P	ADC asynchronous clock source	High speed (ADLPC = 0)	f_{ADACK}	2	3.3	5	MHz	t_{ADACK} = $1/f_{ADACK}$
		Low power (ADLPC = 1)		1.25	2	3.3		

Table 17. ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$) (continued)

C	Characteristic	Conditions	Symbol	Min	Typ[1]	Max	Unit	Comment
P	Conversion time (including sample time)	Short sample (ADLSMP = 0)	t_{ADC}	—	20	—	ADCK cycles	See reference manual for conversion time variances
		Long sample (ADLSMP = 1)		—	40	—		
P	Sample time	Short sample (ADLSMP = 0)	t_{ADS}	—	3.5	—	ADCK cycles	
		Long sample (ADLSMP = 1)		—	23.5	—		
D	Temp sensor slope	–40 °C– 25 °C	m	—	1.646	—	mV/°C	
		25 °C– 85 °C		—	1.769	—		
D	Temp sensor voltage	25 °C	V_{TEMP25}	—	701.2	—	mV	
T	Total unadjusted error	12-bit mode, 3.6> V_{DDAD} > 2.7	E_{TUE}	—	–1 to 3	–2.5 to 5.5	LSB[2]	Includes quantization
T		12-bit mode, 2.7> V_{DDAD} > 1.8V		—	–1 to 3	–3.0 to 6.5		
P		10-bit mode		—	±1	±2.5		
P		8-bit mode		—	±0.5	±1.0		
T	Differential non-linearity	12-bit mode	DNL	—	±1.0	–1.5 to 2.0	LSB[2]	
P		10-bit mode[3]		—	±0.5	±1.0		
P		8-bit mode[3]		—	±0.3	±0.5		
T	Integral non-linearity	12-bit mode	INL	—	±1.5	–2.5 to 2.75	LSB[2]	
T		10-bit mode		—	±0.5	±1.0		
T		8-bit mode		—	±0.3	±0.5		
T	Zero-scale error	12-bit mode	E_{ZS}	—	±1.5	±2.5	LSB[2]	$V_{ADIN} = V_{SSAD}$
P		10-bit mode		—	±0.5	±1.5		
P		8-bit mode		—	±0.5	±0.5		
T	Full-scale error	12-bit mode	E_{FS}	—	±1.0	–3.5 to 1.0	LSB[2]	$V_{ADIN} = V_{DDAD}$
P		10-bit mode		—	±0.5	±1		
P		8-bit mode		—	±0.5	±0.5		
D	Quantization error	12-bit mode	E_Q	—	–1 to 0	—	LSB[2]	
		10-bit mode		—	—	±0.5		
		8-bit mode		—	—	±0.5		
D	Input leakage error	12-bit mode	E_{IL}	—	±2	—	LSB[2]	Pad leakage[4] * R_{AS}
		10-bit mode		—	±0.2	±4		
		8-bit mode		—	±0.1	±1.2		

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